

Low energy semiconductor gas sensor

Features

- High sensitivity to a wide range of gases
- State-of-the-art nanoparticles technology
- Conditioner is not integrated in the package : power efficiency can be optimized to the application
- Long lifetime
- Short to instance response-time
- Environmentally safe
- Low cost at high volume

Description

The AIME GASNP-2024 is a high-sensitivity gas sensor based on WO3 nanoparticles designed to detect oxydable-gases in the air such as ethanol or ammonia.

It features a sensitive layer of nanoparticles deposited on interdigitated aluminum combs on a doped silicon substrate. A polysilicon heating element ensures thermal control of the sensing area.

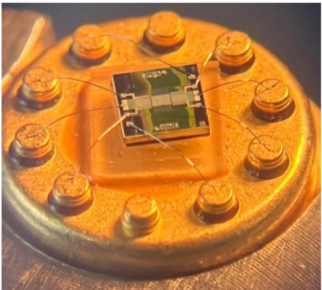


Figure 2: Gas Sensor AIME

Pins configuration

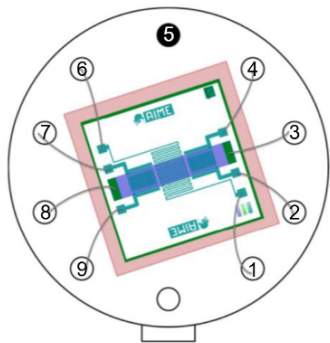


Figure 1: Sensor Pin Layout

Pin number	Function
1-6	Temperature sensor (Aluminum resistor)
2-4	Gas sensor #1
3-8	Thermal resistor (Polysilicon resistor)
7-9	Gas sensor #2
5	NC
10	NC

GENERAL CHARACTERISTICS

Type	Chemical sensor
Materials	<ul style="list-style-type: none">• Silicon• N-doped poly-silicon (heater)• Aluminum (temperature measurements)• Nanoparticles of Tungsten Trioxide (WO₃)
Sensor Type	Active (power supply required)
Gas Measurement	Resistive measure
Temperature Measurement	Resistive measure
Detectable Gases	<ul style="list-style-type: none">• Alcohols (-OH)• Ammonia (NH₃)• Carbon Monoxide (CO)• Dihydrogen (H₂)• Ethanol (C₂H₆O)• Hydrogen Sulfide (SO₂)• Methane (CH₄)• Nitrogen Dioxide (NO₂)
Typical Detection Range	> 1 ppm
Package	TO-5-10 (10 pins)
Head Diameter	9.5 mm
Head Height	4.7 mm
Package Height	25 mm
Pin Diameter	0.6 mm
Mounting	Through hole fixed (THT)

GAS SENSOR CHARACTERISTICS

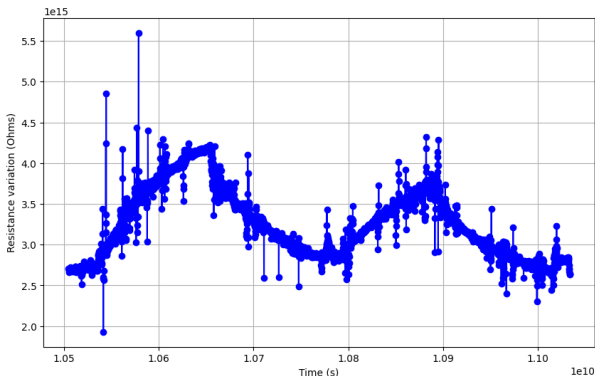


Figure 3: Gas Sensor exposed to ethanol

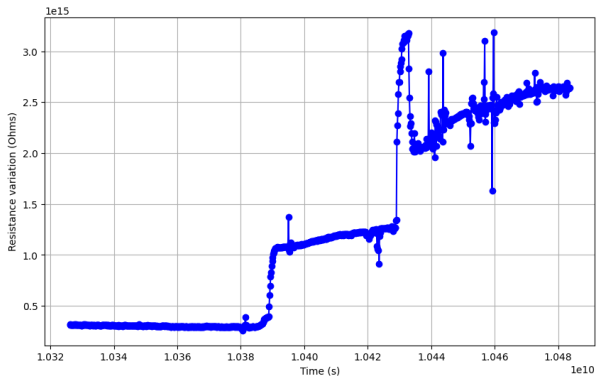


Figure 4: Gas Sensor exposed to ammoniac

ELECTRICAL CHARACTERISTICS

		Units	Min	Typical	Max
Resistance	Gas Sensor	G Ω	0.01	1	100
	Temperature Sensor	Ω	57	65	-
	Heater	Ω	70	85	-
Voltage	Gas Sensor	V	-	3.3	-
	Temperature Sensor	V	3.3	5	-
	Heater	V	10	15	20

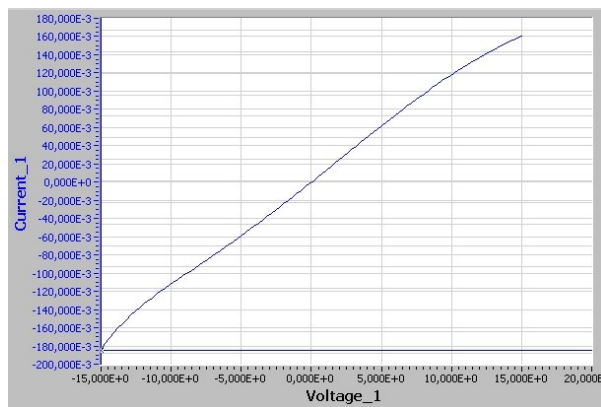


Figure 5: Characteristics of the Poly-silicon resistor

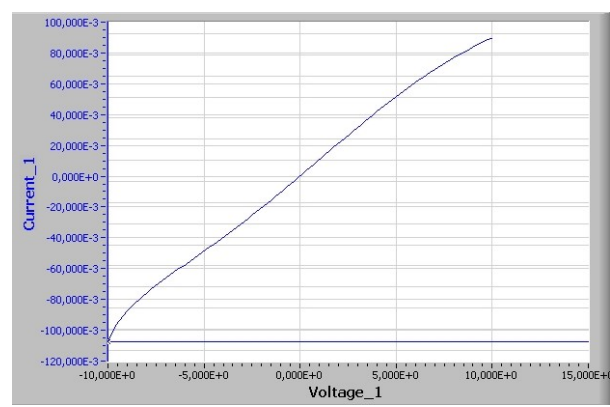


Figure 6: Characteristics of the Aluminium resistor

CONFIGURATION

[b]1

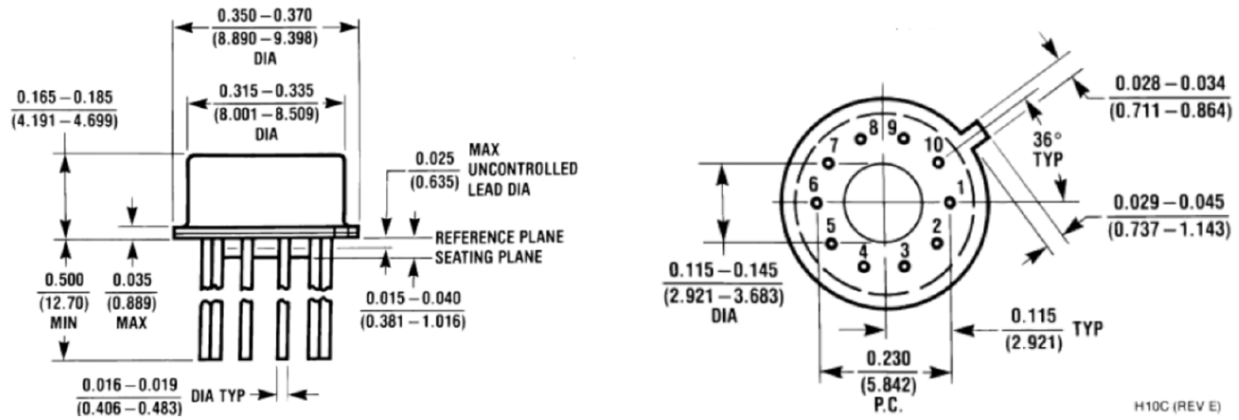


Figure 7: Package Configuration

Application

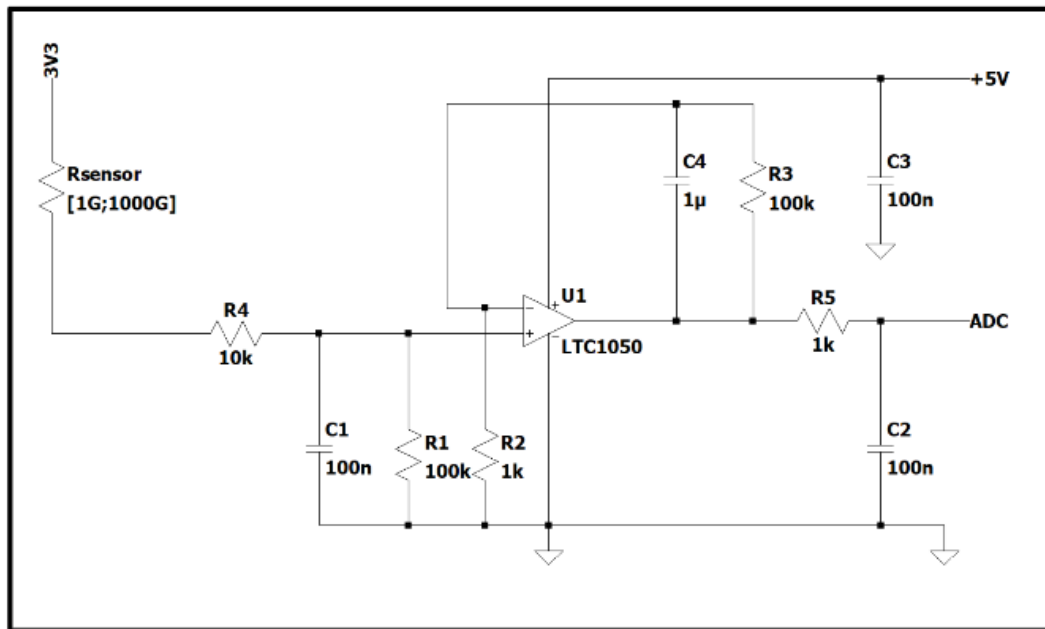


Figure 8: Application example

The resistance of the sensor has a magnitude of Giga Ohm. This means that a voltage divider is not efficient to measure the voltage. The figure above shows the circuit that uses an operational amplifier with a low offset voltage. Therefore, it is not possible to convert the current of the sensor into its resistance using the following formula:

$$R_{sensor} = \left(1 + \frac{R_3}{R_2}\right) \cdot R_1 \cdot \frac{V_{cc}}{V_{adc}} - R_1 - R_5$$